

# yangyan Guo

## List of Publications by Year in descending order

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10  
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1937685

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docs citations

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citing authors

#	ARTICLE	IF	CITATIONS
1	Recent research progress of ferroelectric negative capacitance field effect transistors. Wuli Xuebao/Acta Physica Sinica, 2020, 69, 137701.	0.5	9
2	Influence of dopant concentration on electrical quantum transport behaviors in junctionless nanowire transistors. Chinese Physics B, 2018, 27, 088106.	1.4	8
3	CubemapSLAM: A Piecewise-Pinhole Monocular Fisheye SLAM System. Lecture Notes in Computer Science, 2019, , 34-49.	1.3	6
4	Gate-regulated transition temperatures for electron hopping behaviours in silicon junctionless nanowire transistors. Journal of Semiconductors, 2020, 41, 072905.	3.7	5
5	Transport spectroscopy through dopant atom array in silicon junctionless nanowire transistors. Chinese Physics B, 2018, 27, 097310.	1.4	4
6	Single-electron transport through single and coupling dopant atoms in silicon junctionless nanowire transistor. Chinese Physics B, 2019, 28, 127302.	1.4	4
7	Observation of hopping transitions for delocalized electrons by temperature-dependent conductance in silicon junctionless nanowire transistors*. Chinese Physics B, 2019, 28, 107303.	1.4	2
8	Temperature-dependent subband mobility characteristics in n-doped silicon junctionless nanowire transistor. Chinese Physics B, 2019, 28, 066804.	1.4	1
9	One-Dimensional Transport through Two Subbands in Silicon Junctionless Nanowire Transistors. , 2018, , .		0
10	Low temperature electric field dependent mobility of the current oscillation regime in silicon junctionless nanowire transistor. , 2020, , .		0